Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a TO220 plastic package intended for use in applications requiring high thermal cycling performance and high junction temperature capability ($T_{j(max)} = 150$ °C).

2. Features and benefits

- · High junction operating temperature capability
- High thermal cycling performance
- · High voltage capability
- · Planar passivated for voltage ruggedness and reliability

3. Applications

- Ignition circuits
- Motor control
- · Protection circuits e.g. SMPS inrush current
- · Voltage regulation

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
$I_{T(AV)}$	average on-state current	half sine wave; T _{mb} ≤ 133 °C; <u>Fig. 1</u>	-	-	10.2	А
$I_{T(RMS)}$	RMS on-state current	half sine wave; T _{mb} ≤ 133 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	16	Α
I _{TSM} non-repetitive peak on- state current		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	-	180	А
		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 8.3 \text{ ms}$	-	-	198	А
T _j	junction temperature		-	-	150	°C
Static ch	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 7$	-	-	15	mA
Dynamic	characteristics					
dV _D /dt rate of rise of off-state voltage		V_{DM} = 402 V; T_{j} = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	
2	А	anode	}	A K G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
TYN16-600CT	TO220	TYN16-600CT,127	Tube	50	SOT78	13-Jun-2008

7. Marking

Table 4. Marking codes

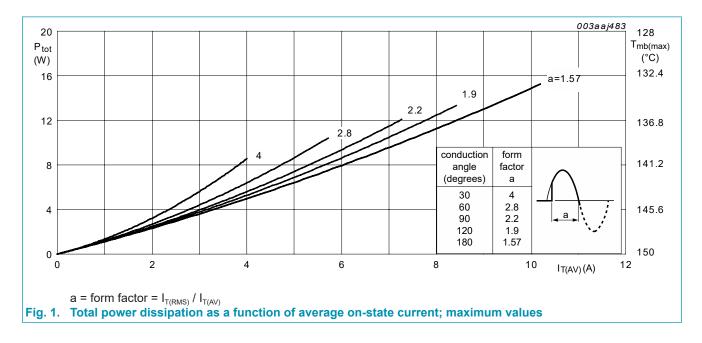
Type number	Marking codes		
	Assembly factory: d	Assembly factory: A	
TYN16-600CT	TYN16 600CT PJdxxxx xx	TYN16 600CT PJAxxxx xx	

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
V_{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 133 °C; <u>Fig. 1</u>	-	10.2	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 133 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	16	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	180	А
		half sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 8.3 \text{ms}$	-	198	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	162	A ² s
dl _⊤ /dt	rate of rise of on-state current	$I_T = 40 \text{ A}$; $I_G = 200 \text{ mA}$; $dI_G/dt = 200 \text{ mA}/\mu\text{s}$	-	50	A/µs
I _{GM}	peak gate current		-	4	А
V_{RGM}	peak reverse gate voltage		-	5	V
P_GM	peak gate power		-	10	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
T _j	junction temperature		-	150	°C



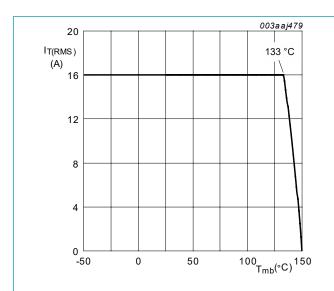
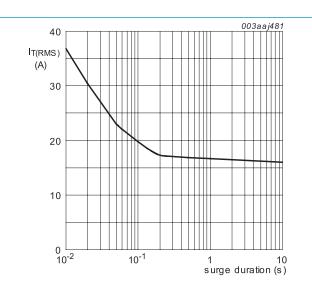
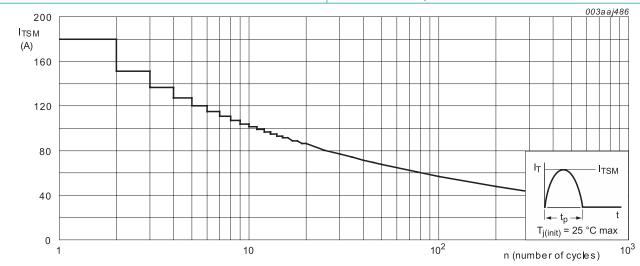


Fig. 2. RMS on-state current as a function of mounting base temperature; maximum values



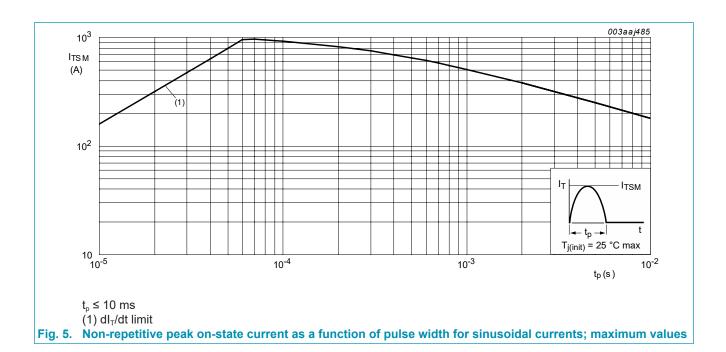
f = 50 Hz; T_{mb} =133 °C Fig. 3. RMS on-state current as a function of surge duration; maximum values



f = 50 Hz

Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	Fig. 6	-	-	1.1	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

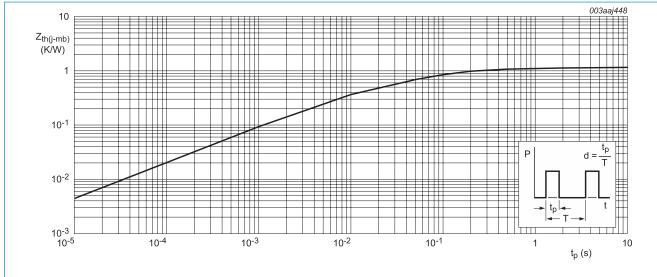


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse width

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics				'	
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 7$	-	-	15	mA
IL	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 8$	-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V_T on-state voltage V_{GT} gate trigger voltage		I _T = 32 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.6	V
		V _D = 12 V; I _T = 0.1 A;T _j = 25 °C; <u>Fig. 11</u>	-	0.7	1.3	V
		V _D = 400V; I _T = 0.1 A;T _j = 150 °C	0.2	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 150 °C	-	0.2	1	mA
I _R	reverse current	V _R = 600 V; T _j = 150 °C	-	0.2	1	mA
Dynamic	characteristics					
		V_{DM} = 402 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs

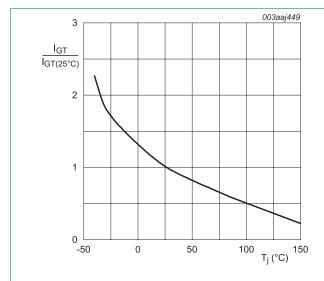


Fig. 7. Normalized gate trigger current as a function of junction temperature

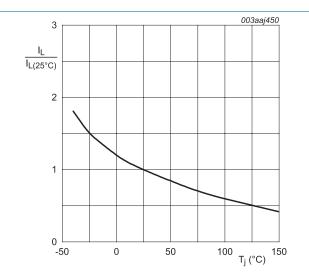


Fig. 8. Normalized latching current as a function of junction temperature

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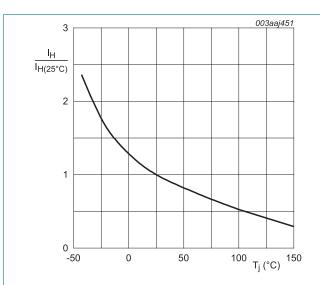
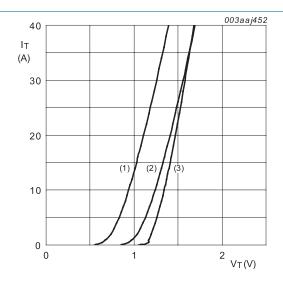


Fig. 9. Normalized holding current as a function of junction temperature



 V_0 = 1.08 V; R_s = 0.0165 Ω (1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values (3) T_j = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

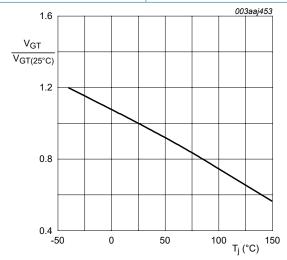
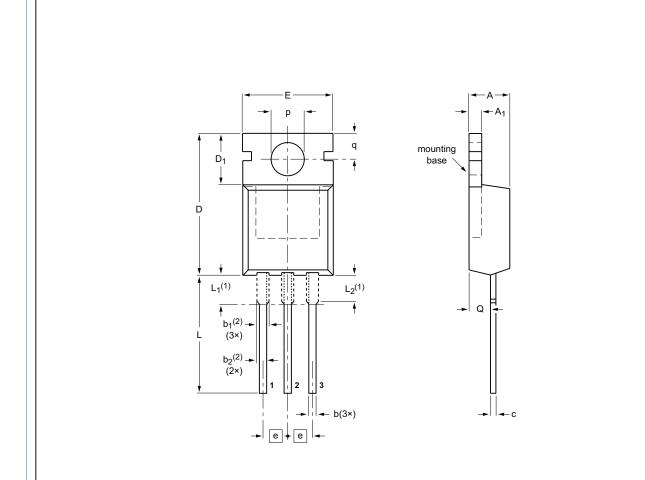


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

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11. Package outline

Assembly factory: d & A



Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

0 5 10 mm scale

DIMENSIONS (mm are the original dimensions)

		•		-		•										
UNIT	Α	A ₁	b	b ₁ ⁽²⁾	b ₂ (2)	С	D	D ₁	E	е	L	L ₁ (1)	L ₂ ⁽¹⁾ max.	р	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

Notes

- Lead shoulder designs may vary.
 Dimension includes excess dambar.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DA		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT78		3-lead TO-220AB	SC-46		08-04-23 08-06-13	

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition				
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.				
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.				
Product Production [short] data sheet		This document contains the product specification.				

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